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# SED Series SED driver with RAM Technical Manual Technical Manual



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### **SED1500 Series Selection Guide**

### ■ LCD drivers with RAM for smalland medium-sized displays

Ultra-low power consumption and on-chip RAM make this series ideal for compact LCD-based equipment.

SED1500 series

Part number	Supply voltage range (V)	LCD voltage range (V)	Duty	Segment	Common	Display RAM (bits)	Microprocessor interface	Frequency (KHz)	Package	Application/additional features
SED1510Doc									Al pad chip	
SED1510D0B									Au bump chip	Small segment-type LCD
SED1510Foc	0.9–6.0	1.8-6.0	1/4	32	4	128	Serial	18 (internal)	QFP12-48pin	display. Command and data interface
SED1510F0E									QFP6-60pin	
SED1511D0A									Al pad chip	Small segment-type LCD dislays. Data only interface
SED1520D0A									Al pad chip	
SED1520D <sub>0B</sub>								18	Au bump chip	
SED1520F0A								(internal,	QFP5-100pin	
SED1520Foc								external)	QFP15-100pin	
SED1520T0A			1/16,1/32	61	16				TCP	Dot-matrix LCD displays Extension driver is the
SED1520DAA			1/10,1/32	01	10				Al pad chip	SED1521.
SED1520DAB								0	Au bump chip	
SED1520FAA								2 (external)	QFP5-100pin	
SED1520Fac								, ,	QFP15-100pin	
SED1520TAA#									TCP	
SED1521D0A									Al pad chip	
SED1521D <sub>0B</sub>								40	Au bump chip	
SED1521F0A								18 (external)	QFP5-100pin	
SED1521Foc									QFP15-100pin	
SED1521T0A#									TCP	Extension driver for the
SED1521DAA		3.5–13	1/8–1/32	80	-				Al pad chip	SED1520 and SED1522
SED1521Dab	2.4–7.0					2,560	8-bit parallel		Au bump chip	
SED1521FAA						,		2 "	QFP5-100pin	
SED1521Fac								(external)	QFP15-100pin	
SED1521TAA#									TCP	
SED152AD0A									Al pad chip	P-substrate version of SED1521
SED1522D0A									Al pad chip	
SED1522D0B								18	Au bump chip	
SED1522F0A								(internal, external)	QFP5-100pin	
SED1522F <sub>0</sub> C								exterriar)	QFP15-100pin	D
SED1522ToA#			1/8,1/16	69	8				TCP	Dot-matrix LCD displays Extension driver is the
SED1522DAA			,						Al pad chip	SED1521.
SED1522DAB								2	Au bump chip	
SED1522FAA								(external)	QFP5-100pin	
SED1522FAC									QFP15-100pin	
SED1522TAA#									TCP	
SED1540D0A								18 (internal)	Al pad chip	
SED1540D <sub>0B</sub>		3.5–11	1/3,1/4	73	3, 4			4 (external)	Au bump chip	Segment-type displays
SED1540F0A									QFP5-100pin	

Part number	Supply voltage range (V)	LCD voltage range (V)	Duty	Segment	Common	Display RAM (bits)	Microprocessor interface	Frequency (KHz)	Package	Application/additional features
SED1560D0A									Al pad chip	
SED1560DAA									Al pad chip	
SED1560D0B			1/48, 1/49						Au bump chip	
SED1560DAB	-		1/64, 1/65	102	65				Au bump chip	
SED1560ToB	-		ŕ						TCP	
SED1560TQA	-								QTCP	
SED1561D0A									Al pad chip	Duilt in a surre since it for LOD
SED1561DAA	-					166×65			Al pad chip	Built-in power circuit for LCD (voltage tripler)
SED1561D <sub>0B</sub>	2.4–6.0	6.0–16.0				bits		18	Au bump chip	SED1560*₀B (1/9 bias) SED1560*AB (1/7 bias)
SED1561DAB	- 2 0.0	0.0 10.0	1/24, 1/25	134	33	5.10			Au bump chip	SED1560*AB (1/7 bias)
SED1561T0B	-		1/32, 1/33						TCP	SED1561*AB (1/5 bias)
SED1561TAB	-								TCP	
SED1561TQA	-								QTCP	
SED1562D0A	-								Al pad chip	
SED1562D08	-		1/16, 1/17						Au bump chip	
SED1562T <sub>0B</sub>	-		(1/5bias)	150	17				TCP	
SED1562TQA	-		(1/55103)				8-bit parallel		QTCP	
SED1565D0B							or Serial		Au bump chip	
SED1565D1B*	-						UI Seliai		Au bump chip	
SED1565D2B	-		1/65						Au bump chip	
SED1565T0A	-				65				TCP	
SED1565T0A SED1565T0B	-		(1/7, 1/9 bias)							
SED1565T08									TCP TCP	
SED156510C SED1566D0B	-								-	
SED1566D1B*	-		1/49						Au bump chip	
	4055	45.460			49	132×65		33	Au bump chip	Built-in power circuit for LCD
SED1566D2B	1.8–5.5	4.5–16.0	(1/6, 1/8 bias)	132		bits		33	Au bump chip	(DC/DC×4)
SED1566T0A									TCP	
SED1567D0B	-								Au bump chip	
SED1567D1B*	-		1/33		00				Au bump chip	
SED1567D2B	-		(1/5, 1/6 bias)		33				Au bump chip	
SED1567ToB	-								TCP	
SED1567Toc	-		4/FF /4/0 1/011 1						TCP	
SED1568D0B	-		1/55 (1/6, 1/8 bias)		55				Au bump chip	
SED1569D0B	-		1/53		53				Au bump chip	
SED1569T**			(1/6, 1/8 bias)			000.00			TCP	
SED1570D0A	2.7–5.5	8.0-20.0	1/64–1/200		_	200×80	4-bit parallel	-	Al pad chip	Built-in self-refreshing function
SED1570D0B						bits			Au bump chip	Puilt in power circuit for LCD
SED1526D*A	-		4/0 1/0	80					Al pad chip	Built-in power circuit for LCD (voltage tripler)
SED1526D*B	-		1/8, 1/9		17				Au bump chip	SED1526*0* (VREG)
SED1526F*A	-	3.5-	1/16, 1/17			00.00	0.17		QFP5-128pin	SED1526*E*
SED1526T*A	2.4-6.0	Supply ×3				80×33	8-bit parallel	20	TCP	(no VREG) SED1526*A*
SED1528D*A		voltage				bits	or Serial		Al pad chip	(redistribution of COMS)
SED1528D*B		3-	1/32, 1/33	64	33				Au bump chip	SED1528 <b>≭</b> 0* (VREG)
SED1528F*A			,						QFP5-128pin	SED1528*E*
SED1528T*A									TCP	(no VREG)

Part number	Supply voltage range (V)	LCD voltage range (V)	Duty	Segment	Common	Display RAM (bits)	Microprocessor interface	Frequency (KHz)	Package	Application/additional features
SED1530D0A									Al pad chip	
SED1530DAA									Al pad chip	
SED1530D0B			1/32, 1/33	100	33				Au bump chip	
SED1530DAB									Au bump chip	
SED1530TAA									TCP	Built-in power circuit for LCD
SED1531D0A									Al pad chip	(voltage quadrupler) SED153**0*
SED1531D0B				132	-	132×65	8-bit parallel		Au bump chip	(Common: Right side)
SED1531T0A	2.4-6.0	4.5–16.0				bits	or Serial	-	TCP	SED153**A* (Common: Both side)
SED1532D0A						DIIS	or Serial		Al pad chip	SED153**B*
SED1532DBA			1/64, 1/65						Al pad chip	(Common: Left side) SED153**F*
SED1532D0B				100	33				Au bump chip	(no VREG)
SED1532DBA				100	33				Au bump chip	
SED1532T0A									TCP	
SED1532TBA									TCP	
SED1535D0B*			1/35	98	35				Au bump chip	

TCP : Tape Carrier Package

### 5. SED1530 Series

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### **OVERVIEW**

The SED1530 series is a single-chip LCD driver for dot-matrix liquid crystal displays (LCD's) which is directly connectable to a microcomputer bus. It accepts 8-bit serial or parallel display data directly sent from a microcomputer and stores it in an on-chip display RAM. It generates an LCD drive signal independent of microprocessor clock.

The use of the on-chip display RAM of  $65 \times 132$  bits and a one-toone correspondence between LCD panel pixel dots and on-chip RAM bits permits implementation of displays with a high degree of

As a total of 133 circuits of common and segment outputs are incorporated, a single chip of SED1530 series can make  $33 \times 100$ dot (16 × 16-dot kanji font: 6 columns × 2 lines) displays, and a single chip of SED1531 can make 65 × 132-dot (kanji font: 8 columns x 4 lines) displays when the SED1531 is combined with the common driver SED1635.

The SED1532 can display the  $65 \times 200$ -dot (or 12-column by 4-line Kanji font) area using two ICs in master and slave modes. As an independent static indicator display is provided for time-division driving, the low-power display is realized during system standby and others.

No external operation clock is required for RAM read/write opera-

tions. Accordingly, this driver can be operated with a minimum current consumption and its on-board low-current-consumption liquid crystal power supply can implement a high-performance handy display system with a minimum current consumption and a smallest LSI configuration.

Two types of SED1530 series are available: one in which common outputs are arranged on a single side and the other in which common outputs are arranged on both sides.

### **FEATURES**

- · Direct RAM data display using the display RAM. When RAM data bit is 0, it is not displayed. When RAM data bit is 1, it is displayed. (At normal display)
- RAM capacity:  $65 \times 132 = 8580$  bits
- · High-speed 8-bit microprocessor interface allowing direct connection to both the 8080 and 6800.
- Serial interface
- · Many command functions: Read/Write Display Data, Display ON/OFF, Normal/Reverse Display, Page Address Set, Set Display Start Line, Set Column Address, Read Status, All Display ON/OFF, Set LCD Bias, Electronic contrast Controls, Read Modify Write, Select Segment Driver Direction, Power Save

• Series specifications (in cases of chip shipments)

Type 1 [VREG (Built-in power supply regulating voltage) Temperature gradient: 0.2% / °C]

Name	Duty	LCD bias	Segment driver	COM driver	Display area	Remarks
SED1530D0*	1/33	1/5, 1/6	100	33	33×100	COM single-side layout
SED1530DA*	1/33	1/5, 1/6	100	33	33×100	COM dual-side layout
SED1531D0*	1/65	1/6, 1/8	132	0	65 × 132	SED1635 is used as the COM.
SED1532D0*	1/65	1/6, 1/8	100	33	65 × 200	COM single-side, right-hand layout
SED1532DB*	1/65	1/6, 1/8	100	33	65 × 200	COM single-side, left-hand layout
SED1535DA*	1/35	1/5, 1/6	98	35	35 × 98	COM both-side layout

Type 2 [VREG Temperature gradient: 0.00% / °C]

Name	Duty	LCD bias	Segment driver	COM driver	Display area	Remarks
SED1530DF*	1/33	1/5, 1/6	100	33	33×100	COM both-side layout
SED1532DE*	1/65	1/6, 1/8	100	33	65 × 200	COM single-side, right-hand layout
SED1533DF*	1/17	1/5	116	17	17×116	COM both-side layout
SED1534DE*	1/9	1/5	124	9	9 × 124	COM single-side layout

: Gold bump

Note: The SED1530 series has the following subcodes depending on their shapes. (The SED1530 examples are given.)

SED1530T\*\* : TCP (The TCP subcode differs from the inherent chip subcode.) SED1530D\*\* : Bear chips SED1530D\*A : Aluminum pad SED1530D\*B

· On-chip LCD power circuit: Voltage booster, voltage regulator, voltage follower  $\times$  4.

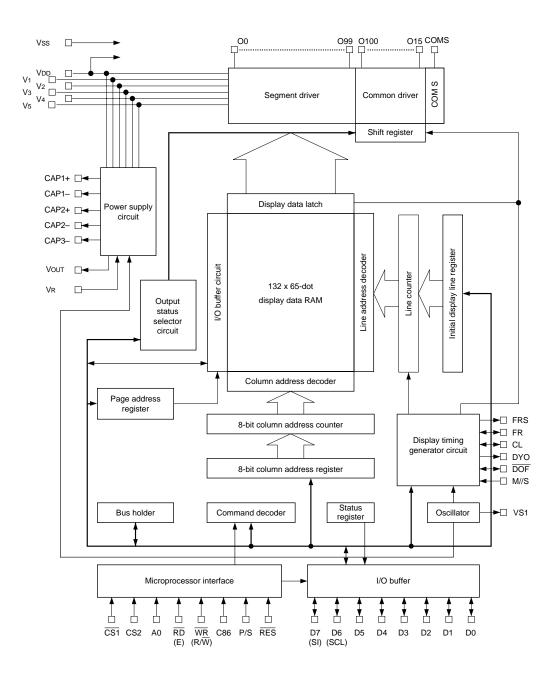
- · On-chip electronic contrast control functions
- · Ultra low power consumption
- $V_{DD}$   $V_{SS}$  -2.4 V to -6.0 V Power supply voltages: V<sub>DD</sub> - V5 -4.5 V to -16.0 V

· Wide operating temperature range:  $Ta = -40 \text{ to } 85^{\circ}\text{C}$ 

- CMOS process
- · Package: TCP and bare chip • Non-radiation-resistant design

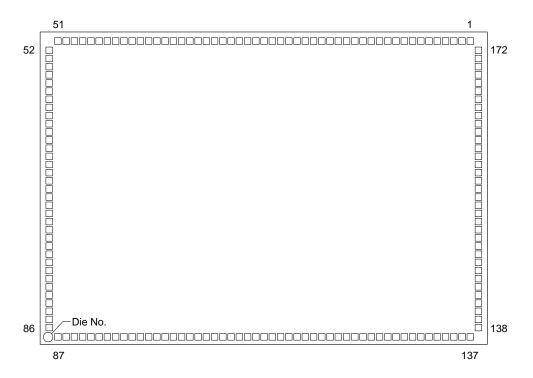
**EPSON** 5-1

### BLOCK DIAGRAM (SED1530D0B)



5–2 **EPSON** 

### PIN ASSIGNMENT SED1530 series chips



Chip Size: 6.65x4.57 mm Pad Pitch: 118 μm (Min)

SED153\*D\*A (Aluminum pad model)

Pad Center Size: 90x90 μm Chip Thickness: 300 μm

 $\begin{array}{lll} SED153*D*B & (Gold \ bump \ model) \\ Bump \ Size: & 76x76 \ \mu m \\ Bump \ Height: & 23\mu m \ (Typ.) \\ Chip \ Thickness: & 625 \ \mu m \end{array}$ 

### **Pad Center Coordinates**

Unit:  $\mu m$ 

PAD	PIN			PAD	PIN			PAD	PIN			PAD	PIN		
No.	Name	х	Υ	No.	Name	Х	Υ	No.	Name	x	Υ	No.	Name	x	Υ
1	0127	2986	2142	51	O5	-2986	2142	101	O55	-1298	-2142	151	O105	3178	-472
2	O128	2862		52	06	-3178	2006	102	O56	-1180	-   -	152	O106		-354
3	O129	2738		53	07		1888	103	O57	-1062		153	O107		-236
4	O130	2614		54	08		1770	104	O58	-944		154	O108		-118
5	O131	2490		55	O9		1652	105	O59	-826		155	O109		0
6	COMS	2366		56	O10		1534	106	O60	-708		156	O110		118
7	FRS	2242		57	011		1416	107	O61	-590		157	0111		236
8	FR	2124		58	O12		1298	108	O62	-472		158	0112		354
9	DYO	2006		59	O13		1180	109	O63	-354		159	O113		472
10	CL	1888		60	014		1062	110	O64	-236		160	0114		590
11	DOF	1770		61	O15		944	111	O65	-118		161	O115		708
12	VS1	1652		62	O16		826	112	O66	0		162	O116		826
13	M/S	1534		63	017		708	113	O67	118		163	O117		944
14	RES	1416		64	O18		590	114	O68	236		164	O118		1062
15	P/S	1298		65	O19		472	115	O69	354		165	O119		1180
16	CS1	1180		66	O20		354	116	O70	472		166	O120		1298
17	CS2	1062		67	O21		236	117	071	590		167	0121		1416
18	C86	944		68	O22		118	118	072	708		168	O122		1534
19	A0	826		69	O23		0	119	073	826		169	O123		1652
20	$\overline{WR}(W/\overline{R})$	708		70	O24		-118	120	074	944		170	0124		1770
21	RD(E)	590		71	O25		-236	121	075	1062		171	O125		1888
22	VDD	354		72	O26		-354	122	076	1180		172	O126	♦	2006
23	D0	236		73	027		-472	123	077	1298					
24	D1	236		74	O28		-590	124	O78	1416					
25	D2	118		75	O29		-708	125	079	1534					
26	D3	0		76	O30		-826	126	O80	1652					
27	D4	-118		77	O31		-944	127	O81	1770					
28	D5	-236		78	O32		-1062	128	O82	1888					
29	D6(SCL)	-354		79	O33		-1180	129	O83	2006					
30	D7(SI)	-472		80	O34		-1298	130	O84	2124					
31	Vss	-590		81	O35		-1416	131	O85	2242					
32	Vout	-708		82	O36		-1534	132	O86	2366					
33	CAP3-	-826		83	O37		-1652	133	O87	2490					
34	CAP1+	-944		84	O38		-1770	134	O88	2614					
35	CAP1-	-1062		85	O39		-1888	135	O89	2738					
36	CAP2+	-1180		86	O40		-2006	136	O90	2862					
37	CAP2-	-1298		87	O41	-2986	-2142	137	O91	2986	♦				
38	V5	-1416		88	O42	-2862		138	O92	3178	-2006				
39	VR	-1534		89	O43	-2738		139	O93		-1888				
40	VDD	-1652		90	O44	-2614		140	O94		-1770				
41	V1	-1770		91	O45	-2490		141	O95		-1652				
42	V2	-1888		92	O46	-2366		142	O96		-1534				
43	V3	-2006		93	O47	-2242		143	O97		-1416				
44	V4	-2124		94	O48	-2124		144	O98		-1298				
45	V5	-2242		95	O49	-2006		145	O99		-1180				
46	O0	-2366		96	O50	-1888		146	O100		-1062				
47	O1	-2490		97	O51	-1770		147	O101		-944				
48	O2	-2614		98	O52	-1652		148	O102		-826				
49	O3	-2738		99	O53	-1534		149	O103		-708				
50	04	-2862	♦	100	O54	-1416	🔻	150	O104	♦	-590				
49	О3	-2738	•	99	O53	-1534		149	O103	•	-708				

5–4 EPSON

### **PIN DESCRIPTION**

### **Power Supply**

Name	I/O		Description									
V <sub>DD</sub>	Supply	+5V power supply	+5V power supply. Connect to microprocessor power supply pin $V_{CC}$ .									
V <sub>SS</sub>	Supply	Ground	Ground									
V1, V2 V3, V4 V5	Supply	impedance-convert for application. Vo $V_{DD} \ge V1 \ge V2 \ge V3$ When the on-chip of are given to V1 to V performed by the S	LCD driver supply voltages. The voltage determined by LCD cell is impedance-converted by a resistive driver or an operational amplifier for application. Voltages should be the following relationship: $V_{DD} \geq V1 \geq V2 \geq V3 \geq V4 \geq V5$ When the on-chip operating power circuit is on, the following voltages are given to V1 to V4 by the on-chip power circuit. Voltage selection is performed by the Set LCD Bias command. (The SED1533 and SED1534 are fixed to 1/5 bias.)									
		SED.	530/SED153	SED1531	SED1532							
		V2 2/5 V3 3/5	•V5 2/6•V5 •V5 4/6•V5	2/6•V5 2/8•V5 4/6•V5 6/8•V5								
			SED1533 SED1534									
		V1 V2 V3 V4	1/5•V5 2/5•V5 3/5•V5 4/5•V5	1/5•V5 2/5•V5 3/5•V5 4/5•V5								

### **LCD Driver Supplies**

Name	I/O	Description	Number of pins
CAP1+	0	DC/DC voltage converter capacitor 1 positive connection	1
CAP1-	0	DC/DC voltage converter capacitor 1 negative connection	1
CAP2+	0	DC/DC voltage converter capacitor 2 positive connection	1
CAP2-	0	DC/DC voltage converter capacitor 2 negative connection	1
CAP3-	0	DC/DC voltage converter capacitor 1 negative connection	1
V <sub>OUT</sub>	0	DC/DC voltage converter output	1
VR	I	Voltage adjustment pin. Applies voltage between V <sub>DD</sub> and V5 using a resistive divider.	1

### **Microprocessor Interface**

Name	I/O	Description	Number of pins
D0 to D7 (SI) (SCL)	I/O	8-bit bi-directional data bus to be connected to the standard 8-bit or 16-bit microprocessor data bus.  When the serial interface selects;  D7: Serial data input (SI)  D6: Serial clock input (SCL)	8
A0	I	Control/display data flag input. It is connected to the LSB of micro- processor address bus. When low, the data on D0 to D7 is control data. When high, the data on D0 to D7 is display data.	1
RES		When RES is caused to go low, initialization is executed.  A reset operation is performed at the RES signal level.	1
CS1 CS2	I	Chip select input. Data input/output is enabled when -CS1 is low and CS2 is high. When chip select is non-active, D0 to D7 will be "HZ".	2
RD (E)	I	When interfacing to an 8080 series microprocessor:     Active low. This input connects the RD signal of the 8080 series microprocessor. While this signal is low, the SED1530 series data bus output is enabled.      When interfacing to a 6800 series microprocessor:     Active high. This is used as an enable clock input pin of the 6800 series microprocessor.	1

### SED1530 Series

Name	I/O			Descr	iption			Number of pins			
WR (R/W)	I	WR is a When in it will be R/W is R/W = "	<ul> <li>Write enable input. When interfacing to an 8080-series microprocessor,</li></ul>								
C86	I	C86 = h	nigh: 6800 s	face select termin series microproces eries microproces	essor inte			1			
P/S	I	Serial da	ta input/par	allel data input se	elect pin.			1			
		P/S	Chip select	Data/command	Data	Read/write	Serial clock				
		"H"	CS1, CS2	A0	D0-D7	RD, WR	_				
		"L"	"L" CS1, CS2 A0 SI(D7) Write only SCL(D6)								
				data can be read 0 to D5 are HZ a			be fixed high				

### **LCD Driver Outputs**

Name	I/O		Description									
M/S	I	signal is outputhe LCD systethe slave oper M/S = high: M/S = low: S	SED1530 series master/slave mode select input. When a necessary signal is output to the LCD, the master operation is synchronized with the LCD system, while when a necessary signal is input to the LCD, the slave operation is synchronized with the LCD system.  M/S = high: Master operation  M/S = low: Slave operation  The following is provided depending on the M/S status.  Model Status OSC Power supply CL FR DYO FRS DOF circuit circuit									
		Model S										
		SED153*D**	/laster	Enabled	Enabled	Output	Output	Output	Output	Output		
		OLD 100 AD A A	Slave	Disabled	Disabled	Input	Input	HZ	HZ	Input		
CL	I/O	slave mode, e combination w common drive	Display clock input/output. When the SED1530 series selects master/ slave mode, each CL pin is connected. When it is used in combination with the common driver, this input/output is connected to common driver YSCL pin.  M/S = high: Output M/S = low: Input								1	
FR	I/O	LCD AC signa slave mode, e When the SEI connected to t M/S = high: 0 M/S = low: In	ach F 01530 he co Output	R pin is co series se mmon driv	nnected. lects mas	ter mod					1	
DYO	I/O	Common drive operation and at slave opera	conne								1	
VS1	0	Internal power	supp	ly voltage	monitor o	output.					1	
DOF	I/O	master/slave r is used in com input is conner M/S = high:	LCD blanking control input/output. When the SED1530 series selects master/slave mode, the respective $\overline{\text{DOF}}$ pin is connected. When it is used in combination with the common driver (SED1635), this output/input is connected to the common driver $\overline{\text{DOFF}}$ pin.  M/S = high: Output M/S = low: Input								1	
FRS	0	Static drive ou This is enable pin. This outp	d only					gether \	with the	FR	1	

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Name	I/O			Descriptio	n		Number of pins
On (SEG n)	0	LCD drive outp	out. The	following assignme	ent is made depen	ding on	
(Com n)				SEG	CO	M	
		SED1530	D0*	O0~O99	O100~O131	O100~O131	
		SED1530 SED1530		O16~O115	O0~O15, O	116~O131	
		SED1531	D0*	O0~O131			
		SED1532 SED1532		O0~O99	O100~O131		
		SED1532	DB*	O32~O131	O0~O31		
		SED1533	DF*	O8~O123	O0~O7, O12	24~O131	
		SED1534	DE*	O0~O123	O124~O131		
		SED1535	Da*	O18~O115	O6~O17, O	116~O131	
		and FR signal.	FR		ut voltage	]	
		RAM data		Normal display	Reverse display		
		н	Н	V <sub>DD</sub>	V2	_	
			L	V5	V3	_	
		0	H .	V <sub>2</sub>	V <sub>DD</sub>	_	
		Davisa	L	V3	V5	-	
		Power save	-	V	DD .		
		levels is select	ed by co	nmon drive output.	data and FR signa		
		Scan data	FR	On output voltage	<u> </u>		
		Н	H L	V <sub>5</sub>			
		L	Н	V1			
		<del>-</del>	L	V4			
		Power save	_	V <sub>DD</sub>			
COMS	0	Effective only SED1535 and When multiple	with the "HZ" with number D1535 a	When it is not used SED1530, SED153 th the SED1531. Its of the SED1530, Stre used, the same Co.	2, SED1533 and S SED1532, SED15	SED1534, 33 and	

Total 172

### **FUNCTIONAL DESCRIPTION**

### **Microprocessor Interface**

### Interface type selection

The SED1530 series can transfer data via 8-bit bi-directional data buses (D7 to D0) or via serial data input (SI). When high or low is selected for the polarity of P/S pin, either 8-bit parallel data input or serial data input can be selected as shown in Table 1. When serial data input is selected, RAM data cannot be read out.

Table 1

P/S	Туре	CS1	CS2	A0	RD	WR	C86	D7	D6	D0 to D5
H	Parallel input	CS1	CS2	A0	RD	WR	C86	D7	D6	D0 to D5
L	Serial input	CS1	CS2	A0	-	-	-	SI	SCL	(HZ)

"-" must always be high or low.

### Parallel input

When the SED1530 series selects parallel input (P/S = high), the 8080 series microprocessor or 6800 series microprocessor can be selected by causing the C86 pin to go high or low as shown in Table 2.

Table 2

C86	Туре	CS1	CS2	A0	RD	WR	D0 to D7
Н	6800 micro- processor bus	CS1	CS2	A0	Е	R/W	D0 to D7
L	8080 micro- processor bus	CS1	CS2	A0	RD	RW	D0 to D7

### **Data Bus Signals**

The SED1530 series identifies the data bus signal according to A0, E,  $R/\overline{W}$ ,  $(\overline{RD}, \overline{WR})$  signals.

Table 3

Common	6800 processor	8080 pr	ocessor	Function
A0	(R/W)	RD	WR	. 4.1333
1	1	0	1	Reads display data.
1	0	1	0	Writes display data.
0	1	0	1	Reads status.
0	0	1	0	Writes control data in internal register. (Command)

### Serial Interface (P/S is low)

The serial interface consists of an 8-bit shift register and a 3-bit counter. The serial data input and serial clock input are enabled when  $\overline{CS1}$  is low and CS2 is high (in chip select status). When chip is not selected, the shift register and counter are reset.

Serial data of D7, D6, ..., D0 is read at D7 in this sequence when serial clock (SCL) goes high. They are converted into 8-bit parallel data and processed on rising edge of every eighth serial clock signal.

The serial data input (S1) is determined to be the display data when A0 is high, and it is control data when A0 is low. A0 is read on rising edge of every eighth clock signal.

Figure 1 shows a timing chart of serial interface signals. The serial clock signal must be terminated correctly against termination reflection and ambient noise. Operation checkout on the actual machine is recommended.

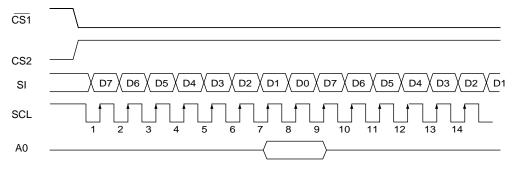


Figure 1

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### **Chip Select Inputs**

The SED1530 series has two chip select pins,  $\overline{CS1}$  and CS2 and can interface to a microprocessor when  $\overline{CS1}$  is low and CS2 is high. When these pins are set to any other combination, D0 to D7 are high impedance and A0,  $\overline{RD}$  and  $\overline{WR}$  inputs are disabled.

When serial input interface is selected, the shift register and counter are reset

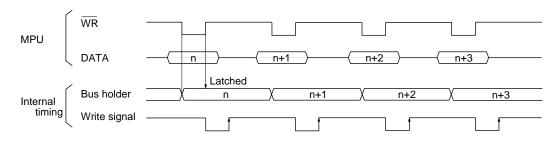
### Access to Display Data RAM and Internal Registers

The SED1530 series can perform a series of pipeline processing between LSI's using bus holder of internal data bus in order to match the operating frequency of display RAM and internal registers with the microprocessor. For example, the microprocessor reads data from display RAM in the first read (dummy) cycle, stores it in bus holder, and outputs it onto system bus in the next data read cycle.

Also, the microprocessor temporarily stores display data in bus holder, and stores it in display RAM until the next data write cycle starts.

When viewed from the microprocessor, the SED1530 series access speed greatly depends on the cycle time rather than access time to the display RAM (t<sub>ACC</sub>). It shows the data transfer speed to/from the microprocessor can increase. If the cycle time is inappropriate, the microprocessor can insert the NOP instruction that is equivalent to the wait cycle setup. However, there is a restriction in the display RAM read sequence. When an address is set, the specified address data is NOT output at the immediately following read instruction. The address data is output during second data read. A single dummy read must be inserted after address setup and after write cycle (refer to Figure 2).

### •Write



### •Read

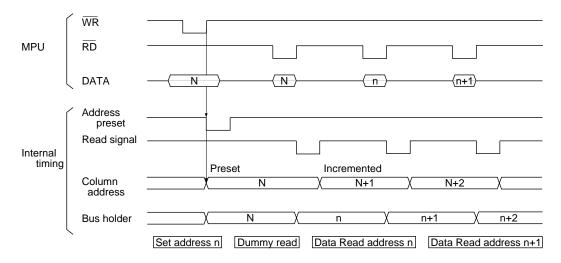


Figure 2

### **Busy Flag**

The Busy flag is set when the SED1530 series starts to operate. During operating, it accepts Read Status instruction only. The busy flag signal is output at pin D7 when Read Status is issued. If the cycle time ( $t_{\rm cyc}$ ) is correct, the microprocessor needs not to check the flag before issuing a command. This can greatly improve the microprocessor performance.

### Initial Display Line Register

When the display RAM data is read, the display line according to

COM0 (usually, the top line of screen) is determined using register data. The register is also used for screen scrolling and page switching.

The Set Display Start Line command sets the 6-bit display start address in this register. The register data is preset on the line counter each time FR signal status changes. The line counter is incremented by CL signal and it generates a line address to allow 132-bit

### **Column Address Counter**

This is a 8 bit presettable counter that provides column address to the display RAM (refer to Figure 4). It is incremented by 1 when a Read/Write command is entered. However, the counter is not incremented but locked if a non-existing address above 84H is specified. It is unlocked when a column address is set again. The Column Address counter is independent of Page Address register.

When ADC Select command is issued to display inverse display, the column address decoder inverts the relationship between RAM column address and display segment output.

### Page Address Register

This is a 4-bit page address register that provides page address to the display RAM (refer to Figure 4). The microprocessor issues Set Page Address command to change the page and access to another page. Page address 8 (D3 is high, but D2, D1 and D0 are low) is

RAM area dedicate to the indicator, and display data D0 is only valid.

### **Display Data RAM**

The display data RAM stores pixel data for LCD. It is a 65-column by 132-row (8-page by 8 bit+1) addressable array. Each pixel can be selected when page and column addresses are specified.

The time required to transfer data is very short because the microprocessor enters D0 to D7 corresponding to LCD common lines as shown in Figure 3. Therefore, multiple SED1530's can easily configure a large display having the high flexibility with very few data transmission restriction.

The microprocessor writes and reads data to/from the RAM through I/O buffer. As LCD controller operates independently, data can be written into RAM at the same time as data is being displayed, without causing the LCD to flicker.

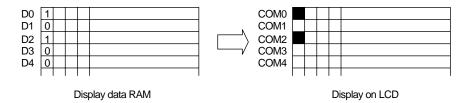


Figure 3

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Relationship between display data RAM and addresses (if initial display line is 1CH):

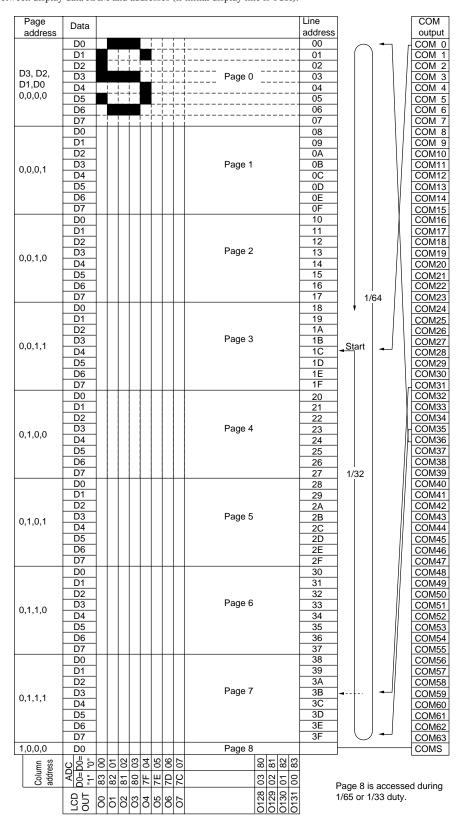


Figure 4

### **Output Status Selector**

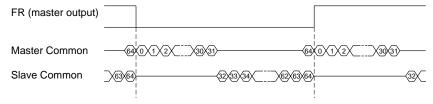
The SED1530 series except SED1531 can set a COM output scan direction to reduce restrictions at LCD module assembly. This scan direction is set by setting "1" or "0" in the output status register D3. Fig.5 shows the status.

Fig. 5 shows the status.

LC	D outp	ut	O0					O131	
ADC	"0	"	0 (H) →					→ 83 (H)	
(D0)	"1	"	83 (H) <b>←</b>		Column addres	SS		<b>←</b> 0 (H)	
					Display data RA	MA			
		D3							
SED153	ODou	0		SEG <sup>2</sup>	100		COM0	COM31	
SED 133	0D0*	1		SEG <sup>2</sup>	COM31	COM0			
SED153	0Da*	0	COM150		SEG100				
SED153	0DF*	1	COM1631		SEG100			COM150	
SED153	1D0*	-			SEG132				
SED153	2D0*	0		SEG <sup>2</sup>	100		COM0	COM31	
SED153	2DE*	1		SEG <sup>2</sup>	100		COM31	COM0	
SED153	2Dp*	0	COM31	0		SEC	€100		
3LD 133	ZDD*	1	COM0	31		SEC	<b>9</b> 100		
SED153	3D=*	0	COM70		SEG116			COM815	
3LD 133	ンレトホ	1	COM815		SEG116			COM70	
SED153	4D=*	0		SEG124 COM0					
	HDE*	1		SEG124 COM7 -					
SED153	SED1535Da*	0	COM170		SEG98			COM1833	
360133	JDA*	1	COM1833		SEG98			COM170	

The COMS pin is assigned to COM32 on SED1530 and it is assigned to COM64 on SED1532 independent from their output status. The COMS pin of the SED1533 is assigned to COM16 and the COMS pin of the SED1534 is assigned to COM8.

Figure 5 shows the COM output pin numbers of SED1532D0\* and SED1532DB\* in the master mode. In the slave mode, COM0 to COM31 must be replaced by COM32 to COM63.



### **Display Timing Generator**

This section explains how the display timing generator circuit operates.

### Signal generation to line counter and display data latch

The display clock (CL) generates a clock to the line counter and a latch signal to the display data latch circuit.

The line address of the display RAM is generated in synchronization with the display clock. 132-bit display data is latched by the display data latch circuit in synchronization with the display clock and output to the segment LCD drive output pin.

The display data is read to the LCD drive circuit completely independent of access to the display data RAM from the microprocessor.

### LCD AC signal (FR) generation

The display clock generates an LCD AC signal (FR). The FR causes the LCD drive circuit to generate a AC drive waveform. It generates a 2-frame AC drive waveform.

When the SED1530 is operated in slave mode on the assumption of multi-chip, the FR pin and CL pin become input pins.

### Common timing signal generation

The display clock generates an internal common timing signal and a start signal (DYO) to the common driver. A display clock resulting from frequency division of an oscillation clock is output from the CL pin.

When an AC signal (FR) is switched, a high pulse is output as a DYO output at the training edge of the previous display clock.

Refer to Fig. 6. The DYO output is output only in master mode. When the SED1530 series is used for multi-chip, the slave requires to receive the FR, CL, DOF signals from the master.

Table 4 shows the FR, CL, DYO and DOF status.

Table 4

Model	Operation mode	FR	CL	DYO	DOF	
SED153*D**	Master	Output	Output	Output	Output	
3ED133*D**	Slave	Input	Input	Hz	Input	

HZ denotes a high-impedance status.

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Example of SED1530D0B 1/33 duty

### Dual-frame AC driver waveforms

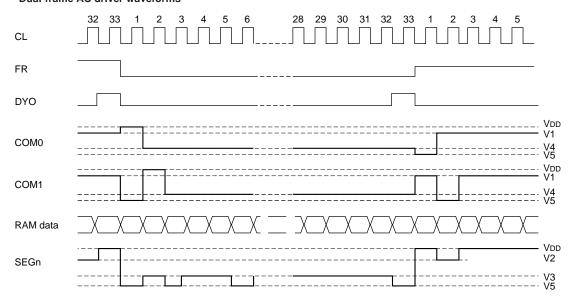


Fig. 6

### Display Data Latch Circuit.

This circuit temporarily stores (or latches) display data (during a single common signal period) when it is output from display RAM to LCD panel driver circuit. This latch is controlled by Display in normal/in reverse Display ON/OFF and Static All-display on commands. These commands do not alter the data.

### **LCD** Driver

This is a multiplexer circuit consisting of 133 segment outputs to generate four-level LCD panel drive signals. The LCD panel drive voltage is generated by a specific combination of display data, COM scan signal, and FR signal. Figure 8 gives an example of SEG and COM output waveforms.

### **Oscillator Circuit**

This is an oscillator having a complete built-in type CR, and its output is used as the display timing signal source or as the clock for voltage booster circuit of the LCD power supply.

The oscillator circuit is available in master mode only.

The oscillator signal is divided and output as display clock at CL pin.

### **Power Supply Circuit**

The power supply circuit generates voltage to drive the LCD panel at low power consumption, and is available in SED1530 master mode only. The power supply circuit consists of a voltage booster voltage regulator, and LCD drive voltage follower.

The power supply circuit built in the SED1530 series is set for a small-scale LCD panel and is inappropriate to a large-pixel panel and a large-display-capacity LCD panel using multiple chips. As the large LCD panel has the dropped display quality due to a large load capacity, it must use an external power source.

The power circuit is controlled by Set Power Control command. This command sets a three-bit data in Power Control register to select one of eight power circuit functions. The external power supply and part of internal power circuit functions can be used simultaneously. The following explains how the Set Power Control command works.

[Control by Set Power Control command]

D2 turns on when triple booster control bit goes high, and D2 turns off when this bit goes low.

D1 turns on when voltage regulator control bit goes high, and D1 turns off when this bit goes low.

D0 turns on when voltage follower control bit goes high, and D0 turns off when this bit goes low.

[Practical combination examples]

Status 1: To use only the internal power supply.

Status 2: To use only the voltage regulator and voltage follower.

Status 3: To use only the voltage follower. input the external voltage as V5=Vout.

Status 4: To use only an external power supply because the internal power supply does not operate.

- \* The voltage booster terminals are CAP1+, CAP1-, CAP2+, CAP2- and CAP3-.
- \* Combinations other than those shown in the above table are possible but impractical.

	D2 D1 D0	Voltage booster	Voltage regulator	Voltage follower	External voltage input	Voltage booster terminal	Voltage regulator terminal
1	1 1 1	ON	ON	ON	_	Used	Used
2	0 1 1	OFF	ON	ON	V <sub>OUT</sub>	OPEN	Used
3	0 0 1	OFF	OFF	ON	V <sub>5</sub>	OPEN	OPEN
4	0 0 0	OFF	OFF	OFF	V <sub>1</sub> to V <sub>5</sub>	OPEN	OPEN

### **Booster circuit**

If capacitors C1 are inserted between CAP1+ and CAP1-, between CAP2+ and CAP2-, CAP1+ and CAP3- and VSS and VOUT, the potential between VDD and VSS is boosted to quadruple toward the negative side and it is output at VOUT.

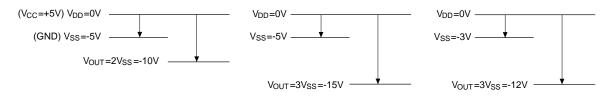
For triple boosting, remove only capacitor C1 between CAP+1 and CAP3- from the connection of quadruple boosting operation and jumper between CAP3- and VOUT. The triple boosted voltage appears at VOUT (CAP3-).

For double boosting, remove only capacitor C1 between CAP2+ and CAP2- from the connection of triple boosting operation, open CAP+2 and jumper between CAP2- and VOUT (CAP3-). The double boosted voltage appears at VOUT (CAP3-, CAP2-).

For quadruple boosting, set a VSS voltage range so that the voltage at VOUT may not exceed the absolute maximum rating.

As the booster circuit uses signals from the oscillator circuit, the oscillator circuit must operate.

Subsection 10.1.1 gives an external wiring example to use master and slave chips when on-board power supply is active.



Potential during double boosting

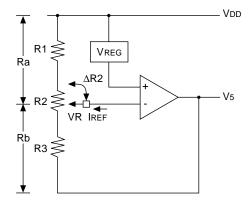
Potential during triple boosting

Potential during quadruple boosting

### Voltage regulator circuit

The boosting voltage occurring at  $V_{OUT}$  is sent to the voltage regulator and the  $V_5$  liquid crystal display (LCD) driver voltage is output. This  $V_5$  voltage can be determined by the following equation when resistors Ra and Rb (R1, R2 and R3) are adjusted within the range of  $|V_5| < |V_{OUT}|$ .

V5=(1+ 
$$\frac{Rb}{Ra}$$
) VREG+IREF · Rb  
=(1+  $\frac{R3+R2-\Delta R2}{R1+\Delta R2}$ ) VREG  
+IREF · (R3+R2- $\Delta$ R2)



 $V_{REG}$  is the constant voltage source of the IC, and in case of Type 1, it is constant and  $V_{REG}\!\!=\!\!-2.55~V$  (if  $V_{DD}$  is 0 V), In case of Type 2,  $V_{REG}\!\!=\!\!V_{SS}$  (VDD basis). To adjust the  $V_5$  output voltage, insert a variable resistor between  $V_R,V_{DD}$  and  $V_5$  as shown. A combination of R1 and R3 constant resistors and R2 variable resistor is recommended for fine-adjustment of  $V_5$  voltage.

Setup example of resistors R1, R2 and R3:

When the Electronic Volume Control Function is OFF (electronic volume control register values are (D4,D3,D2,D1,D0)=(0,0,0,0,0)):

• R1 + R2 + R3 = 5M $\Omega$  ...... ② (Determined by the current passing between  $V_{DD}$  and  $V_5$ )

• Variable voltage range by R2  $V_5 = -6$  to -10 V (Determined by the LCD characteristics)  $\Delta R2 = O\Omega$ ,  $V_{REG} = -2.55$ V

To obtain 
$$V_5 = -10$$
 V, from equation ①:  $R2 + R3 = 2.92 \times R1$  ...... ③  $\Delta R2 = R2$ ,  $V_{REG} = -2.55$ V
To obtain  $V_5 = -6$  V, from equation ①:  $1.35 \times (R1 + R2) = R3$  ....... ④

From equations 2, 3 and 4:

R1=1.27MΩ R2=0.85MΩR3=2.88MΩ

The voltage regulator circuit has a temperature gradient of approximately -0.2%/°C as the  $V_{REG}$  voltage. To obtain another temperature gradient, use the Electronic Volume Control Function for software processing using the MPU.

As the  $V_R$  pin has a high input impedance, the shielded and short lines must be protected from a noise interference.

### Voltage regulator using the Electronic Volume Control Function

The Electronic Volume Control Function can adjust the intensity (brightness level) of liquid crystal display (LCD) screen by command control of V<sub>5</sub> LCD driver voltage.

This function sets five-bit data in the electronic volume control register, and the  $V_5$  LCD driver voltage can be one of 32-state voltages.

To use the Electronic Volume Control Function, issue the Set Power Control command to simultaneously operate both the voltage regulator circuit and voltage follower circuit.

Also, when the boosting circuit is off, the voltage must be supplied from  $V_{\text{OUT}}$  terminal.

When the Electronic Volume Control Function is used, the  $V_5$  voltage can be expressed as follows:

$$V_5 = (1 + \frac{Rb}{Ra}) V_{REG} + Rb \times \Delta I_{REF} \dots$$

Variable voltage range

The increased  $V_5$  voltage is controlled by use of  $I_{REF}$  current source of the IC. (For 32 voltage levels,  $\Delta I_{REF} = I_{REF}/31$ )

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The minimum setup voltage of the  $V_5$  absolute value is determined by the ratio of external Ra and Rb, and the increased voltage by the Electronic Volume Control Function is determined by resistor Rb. Therefore, the resistors must be set as follows:

1) Determine Rb resistor depending on the  $V_5$  variable voltage range by use of the Electronic Volume Control.

$$Rb = \frac{V_5 \text{ variable voltage range}}{I_{REF}}$$

2) To obtain the minimum voltage of the  $V_5$  absolute value, determine Ra using the Rb of Step 1) above.

$$Ra = \frac{Rb}{\frac{V_5}{V_{REG}} - 1} \qquad \{V_5 = (1 + Rb/Ra) \times V_{REG}\}$$

The SED1526 series have the built-in  $V_{REG}$  reference voltage and  $I_{REF}$  current source which are constant during voltage variation. However, they may change due to the variation occurring in IC manufacturing and due to the temperature change as shown below. Consider such variation and temperature change, and set the Ra and Rb appropriate to the LCD used.

$$\begin{array}{lll} V_{REG} = -2.55V \pm 0.20V \ (Type1) & V_{REG} = -0.2\%^{\circ}C \\ V_{REG} = V_{SS} \ (V_{DD} \ basis) \ (Type2) & V_{REG} = -0.00\%^{\circ}C \\ I_{REF} = -3.2\mu A \pm 40\% \ (For \ 16 \ levels) & I_{REF} = 0.023\mu A^{\circ}C \\ -6.5\mu A \pm 40\% \ (For \ 32 \ levels) & 0.052\mu A^{\circ}C \end{array}$$

Ra is a variable resistor that is used to correct the  $V_5$  voltage change due to  $V_{REG}$  and  $I_{REF}$  variation. Also, the contrast adjustment is recommended for each IC chip.

Before adjusting the LCD screen contrast, set the electronic volume control register values to (D4,D3,D2,D1,D0)=(1,0,0,0,0) or (0,1,1,1,1) first.

When not using the Electronic Volume Control Function, set the register values to (D4,D3,D2,D1,D0)=(0,0,0,0,0) by sending the  $\overline{RES}$  signal or the Set Electronic Volume Control Register command.

Setup example of constants when Electronic Volume Control Function is used:

 $V_5$  maximum voltage:  $V_5 = -6 \text{ V}$  (Electronic volume control

register values (D4,D3,D2,D1,D0) =

(0,0,0,0,0)

 $V_5$  minimum voltages:  $V_5 = -10 \text{ V}$  (Electronic volume control

register values (D4,D3,D2,D1,D0) =

(1,1,1,1,1)

V<sub>5</sub> variable voltage range: 4 V Variable voltage levels: 32 levels

1) Determining the Rb:

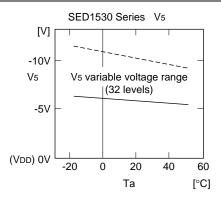
$$R3 = \ \frac{V_5 \ variable \ voltage \ range}{\mid I_{REF} \mid} \ = \frac{4V}{6.5 \mu A} \ \underline{Rb = 625 K\Omega}$$

2) Determining the Ra:

$$Ra = \frac{Rb}{\frac{V_5 max}{V_{REG}} - 1} = \frac{-625k\Omega}{\frac{-6V}{-2.55V} - 1}$$

$$Ra = 462K\Omega$$

$$\begin{array}{l} Ta{=}25^{\circ}C \\ V_5max = (1{+}Rb/Ra) \times V_{REG} \\ = (1{+}625k/442k) \times (-2.55V) \\ = -6.0V \\ V_5min = V_5 max + Rb \times I_{REF} \\ = -6V + 625k \times (-6.5\mu A) \\ = -10.0V \end{array}$$



$$\begin{array}{l} Ta = -10^{\circ}C \\ V_{5}max = (1 + Rb/Ra) \times V_{REG} & (Ta = -10^{\circ}C) \\ = (1 + 625k/462k) \times (-2.55V) \\ \times \{1 + (-0.2\%/^{\circ}C) \times (-10^{\circ}C - 25^{\circ}C)\} \\ = -6.42V \\ V_{5}min = V_{5}max + Rb \times I_{REF} & (Ta = -10^{\circ}C) \\ = -6.42V + 625k \\ \times \{-6.5\mu A + (0.052\mu A/^{\circ}C) \times (-10^{\circ}C - 25^{\circ}C)\} \\ = -11.63V \end{array}$$

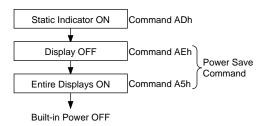
$$\begin{array}{l} \text{Ta=-50°C} \\ V_5 \text{max} = (1 + \text{Rb/Ra}) \times V_{REG} & (\text{Ta=50°C}) \\ = (1 + 625 \text{k}/462 \text{k}) \times (-2.55 \text{V}) \\ \times \{1 + (-0.2\% \text{°C}) \times (50 \text{°C} - 25 \text{°C})\} \\ = -5.7 \text{V} \\ V_5 \text{min} = V_5 \text{max} + \text{Rb} \times I_{REF} & (\text{Ta=50°C}) \\ = -5.7 \text{V} + 625 \text{k} \\ \times \{-6.5 \mu \text{A} + (0.052 \mu \text{A}/\text{°C}) \times (50 \text{°C} - 25 \text{°C})\} \\ = -8.95 \text{V} \end{array}$$

The margin must also be determined in the same procedure given above by considering the  $V_{REG}$  and  $I_{REF}$  variation. This margin calculation results show that the  $V_5$  center value is affected by the  $V_{REG}$  and  $I_{REF}$  variation. The voltage setup width of the Electronic Volume Control depends on the  $I_{REF}$  variation. When the typical value of 0.2 V/step is set, for example, the maximum variation range of 0.12 to 0.28 V must be considered.

In case of Type 2, it so becomes that  $V_{REG} = V_{SS}$  ( $V_{DD}$  basis) and there is no temperature gradient. However,  $I_{REF}$  carries the same temperature characteristics as with Type 1.

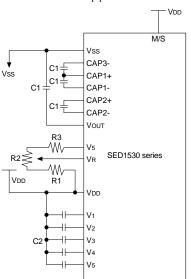
### Command Sequence when Built-in Power Supply is Turned OFF

To turn off the built-in power supply, follow the command sequence as shown below to turn it off after making the system into the standby mode.

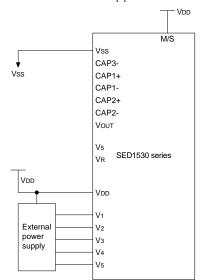


### Voltage generator circuit

when the on-chip power circuit is used



when the on-chip power circuit is used



Reference setup value: SED1530 V5 = -7 to -9 V

SED1531 V5  $\rightleftharpoons$  -11 to -13 V (variable) SED1532 V5  $\rightleftharpoons$  -11 to -13 V (variable)

	SED1530	SED1531	SED1532		
C1	1.0~4.7 uF	1.0~4.7 uF	1.0~4.7 uF		
C2	0.22~0.47 uF	0.47~1.0 uF	0.47~1.0 uF		
R1	700 ΚΩ	1 ΜΩ	1 ΜΩ		
R2	200 ΚΩ	200 ΚΩ	200 ΚΩ		
R3	$1.6~\mathrm{M}\Omega$	$4~\mathrm{M}\Omega$	4 MΩ		
LCD SIZE	16 × 50 mm	32 × 64 mm	32 × 100 mm		
DOT CONFIGURATION	32×100	64×128	64×200		

- As the input impedance of VR is high, a noise protection using short wire and cable shield is required.
- \*2: C1 and C2 depend on the capacity of the LCD panel to be driven. Set a value so that the LCD drive voltage may be stable.

### [Setup example]

Turn on the voltage regulator and voltage follower and give an external voltage to Vout. Display a horizontal-stripe LCD heavy load pattern and determine C2 so that the LCD drive voltage (V1 to V5) may be stable. However, the capacity value of C2 must be all equal. Next, turn on all the on-board power supplies and determine C1.

\*3: LCD SIZE means the length and breadth of the display portion of the LCD panel.

Model	LCD drive voltage					
SED1530	1/5 or 1/6 bias					
SED1531	1/6 or 1/8 bias					
SED1532						

### **Reset Circuit**

When the RES input goes low, this LSI is initialized.

Initialized status

- 1. Display OFF
- 2. Normal display
- 3. ADC select: Normal display (ADC command D0 = low)
- 4. Read modify write OFF
- 5. Power control register (D2, D1, D0) = (0, 0, 0)
- 6. Register data clear in serial interface
- LCD power supply bias ratio 1/6 (SED1530), 1/8 (SED1531, SED1532)
- 8. Static indicator: OFF
- 9. Display start line register set at line 1
- 10. Column address counter set at address 0
- 11. Page address register set at page 0
- 12. Output status register (D3) = (0)
- 13. Electronic control register set at 0
- 14. Test command OFF

As seen in 11. Microprocessor Interface (Reference Example), connect the RES pin to the reset pin of the microprocessor and initialize the microprocessor at the same time.

In case the SED1530 series does not use the internal LCD power supply circuit, the  $\overline{RES}$  must be low when the external LCD power supply is turned on.

When  $\overline{RES}$  goes low, each register is cleared and set to the above initialized status. However, it has no effect on the oscillator circuit and output pins (FR, CL, DYO, D0 to D7).

The initialization by RES pin signal is always required during power-on. If the control signal from the MPU is HZ, an overcurrent may flow through the IC. A protection is required to prevent the HZ signal at the input pin during power-on.

Be sure to initialize it by  $\overline{RES}$  pin when turning on the power supply. When the reset command is used, only parameters 8 to 14 in the above initialization are executed.

5–16 **EPSON** 

5-17

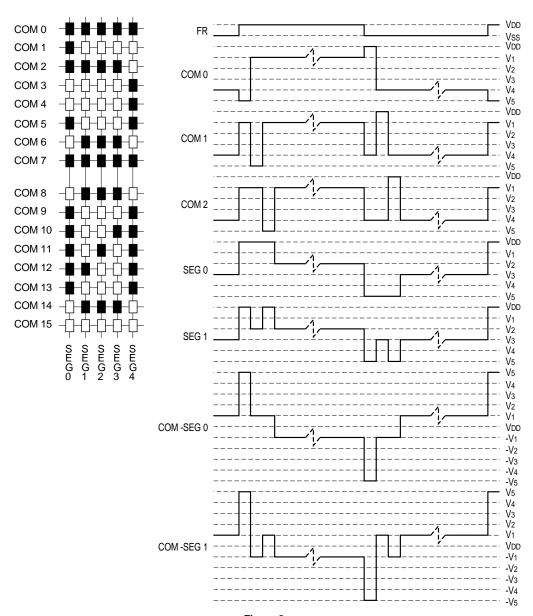


Figure 8

### **COMMANDS**

The SED1530 series uses a combination of A0,  $\overline{RD}$  (E) and  $\overline{WR}$  (R/ $\overline{W}$ ) signals to identify data bus signals. As the chip analyzes and executes each command using internal timing clock only regardless of external clock, its processing speed is very high and its busy check is usually not required. The 8080 series microprocessor interface enters a read status when a low pulse is input to the  $\overline{RD}$  pin and a write status when a low pulse is input to the  $\overline{WR}$  pin. The 6800 series microprocessor interface enters a read status when a high pulse is input to the  $\overline{RD}$  pin and a write status when a low pulse is input to this pin. When a high pulse is input to the E pin, the command is activated. (For timing, see Timing Characteristics.) Accordingly, in the command explanation and command table,  $\overline{RD}$  (E) becomes 1 (high) when the 6800 series microprocessor interface reads status or display data. This is an only different point from the 8080 series microprocessor interface.

Taking the 8080 series microprocessor interface as an example, commands will be explained below.

When the serial interface is selected, input data starting from D7 in sequence.

### · Command set

(1) Display ON/OFF

Alternatively turns the display on and off.

ſ			R/W								
	A0	RD	WR	D7	D6	D5	D4	D3	D2	D1	D0
	0	1	0	1	0	1	0	1	1	1	D

The display turns off when D goes low, and it turns on when D goes high.

### (2) Start Display Line

Specifies line address (refer to Figure 4) to determine the initial display line, or COMO. The RAM display data becomes the top line of LCD screen. It is followed by the higher number of lines in ascending order, corresponding to the duty cycle. When this command changes the line address, the smooth scrolling or page change takes place.

		R/W								
A0	RD	WR	D7	D6	D5	D4	D3	D2	D1	D0
0	1	0	0	1	A5	A4	А3	A2	A1	A0

High-order bit

A5	A4	АЗ	A2	A1	A0	Line address
0	0	0	0	0	0	0
0	0	0	0	0	1	1 1
0	0	0	0	1	0	2
			:			:
1	1	1	1	1	0	62
1	1	1	1	1	1	63

### (3) Set Page Address

Specifies page address to load display RAM data to page address register. Any RAM data bit can be accessed when its page address and column address are specified. The display remains unchanged even when the page address is changed. Page address 8 is the display RAM area dedicate to the indicator, and only D0 is valid for data change.

A0		R/W WR		D6	D5	D4	D3	D2	D1	D0
0	1	0	1	0	1	1	АЗ	A2	A1	A0

A3	A2	A1	A0	Page Address
0	0	0	0	0
0	0	0	1	1
0	0	1	0	2
0	0	1	1	3
0	1	0	0	4
0	1	0	1	5
0	1	1	0	6
0	1	1	1	7
1	0	0	0	8

### (4) Set Column Address

Specifies column address of display RAM. Divide the column address into 4 higher bits and 4 lower bits. Set each of them succession. When the microprocessor repeats to access to the display RAM, the column address counter is incremented by 1 during each access until address 132 is accessed. The page address is not changed during this time.

Higher bits Lower bits

A0		R/W WR		D6	D5	D4	D3	D2	D1	D0
0	1	0	0	0	0	1	Α7	A6	A5	A4
0	1	0	0	0	0	0	АЗ	A2	A1	A0

A7	A6	A5	A4	АЗ	A2	A1	Α0	Column address
0	0	0	0	0	0	0	0	0
0	0	0	0	0	0	0	1	1
				:				:
1	0	0	0	0	0	1	1	131

### (5) Read Status

A0	_	R/W WR		D6	D5	D4	D3	D2	D1	D0
0	0	1	BUSY	ADC	ON/OFF	RESET	0	0	0	0

BUSY: When high, the SED1526 series is busy due to internal operation or reset. Any command is rejected until BUSY goes low. The busy check is not required if enough time is provided for each cycle.

ADC: Indicates the relationship between RAM column address and segment drivers. When low, the display is normal and column address "131-n" corresponds to segment driver n. When high, the display is reversed and column address n corresponds to segment driver n.

ON/OFF: Indicates whether the display is on or off. When goes low, the display turns on. When goes high, the display turns off. This is the opposite of Display ON/OFF command.

RESET: Indicates the initialization is in progress by RES signal or by Reset command. When low, the display is on. When high, the chip is being reset.

### (6) Write Display Data

Writes 8-bit data in display RAM. As the column address is incremented by 1 automatically after each write, the microprocessor can continue to write data of multiple words.

A0	$\frac{E}{RD}$	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0
1	1	0			W	rite da	ata			

### (7) Read Display Data

Reads 8-bit data from display RAM area specified by column address and page address. As the column address is incremented by 1 automatically after each write, the microprocessor can continue to read data of multiple words. A single dummy read is required immediately after column address setup. Refer to the display RAM section of FUNCTIONAL DESCRIPTION for details. Note that no display data can be read via the serial interface.

A0	RD	WR	D7	D6	D5	D4	D3	D2	D1	D0
1	0	1			Re	ad da	ata			

### (8) ADC Select

Changes the relationship between RAM column address and segment driver. The order of segment driver output pins can be reversed by software. This allows flexible IC layout during LCD module assembly. For details, refer to the column address section of Figure 4. When display data is written or read, the column address is incremented by 1 as shown in Figure 4.

	A0	E RD	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0
ľ	0	1	0	1	0	1	0	0	0	0	D

When D is low, the right rotation (normal direction). When D is high, the left rotation (reverse direction).

### (9) Normal/Reverse Display

Reverses the Display ON/OFF status without rewriting the contents of the display data RAM.

A0	E RD	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0
0	1	0	1	0	1	0	0	1	1	D

When D is low, the RAM data is high, being LCD ON potential (normal display).

When D is high, the RAM data is low, being LCD ON potential (reverse display).

### (10) Entire Display ON

Forcibly turns the entire display on regardless of the contents of the display data RAM. At this time, the contents of the display data RAM are held.

This command has priority over the Normal/Reverse Display command. When D is low, the normal display status is provided.

A0	E RD	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0
0	1	0	1	0	1	0	0	1	0	D

When D is high, the entire display ON status is provided. If the Entire Display ON command is executed in the display OFF status, the LCD panel enters Power Save mode. Refer to the Power Save section for details.

### (11) Set LCD Bias

Selects a bias ratio of the voltage required for driving the LCD. This command is enabled when the voltage follower in the power supply circuit operates.

(The LCD bias setting command is invalid for the SED1533 and SED1534. They are being fixed to the 1/5 bias.)

	E	R/W								
A0	RD	WR	D7	D6	D5	D4	D3	D2	D1	D0
0	1	0	1	0	1	0	0	0	1	D

The potential V5 is resistively divided inside the IC to produce potentials V1, V2, V3 and V4 which are necessary to drive the LCD. The bias ratio can be selected using the LCD bias setting command. (The SED1533 and SED1534 are fixed to 1/5 bias.)

Moreover, the potentials V<sub>1</sub>, V<sub>2</sub>, V<sub>3</sub> and V<sub>4</sub> are converted in the impedance and supplied to the LCD drive circuit.

Model	Bias ratio of LCD power supply
SED1530	1/5 bias or 1/6 bias
SED1531	1/6 bias or 1/8 bias
SED1532	1/6 blas of 1/8 blas
SED1533	A/F bion
SED1534	1/5 bias

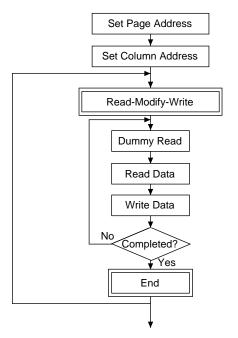
### (12) Read-Modify-Write

A pair of Read-Modify-Write and End commands must always be used. Once Read-Modify-Write is issued, column address is not incremented by Read Display Data command but incremented by Write Display Data command only. It continues until End command is issued. When the End is issued, column address returns to the address when Read-Modify-Write was issued. This can reduce the microprocessor load when data of a specific display area is repeatedly changed during cursor blinking or others.

A0	$\frac{E}{RD}$	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0
0	1	0	1	1	1	0	0	0	0	0

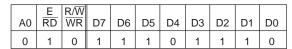
Note: Any command except Read/Write Display Data and Set Column Address can be issued during Read-Modify-Write mode.

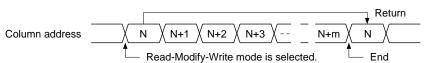
### · Cursor display sequence



### (13) End

Cancels Read-Modify-Write mode and returns column address to the original address (when Read-Modify-Write was issued).





### (14) Reset

Resets the Initial Display Line register, Column Address counter, Page Address register, and output status selector circuit to their initial status. The Reset command does not affect on the contents of display RAM. Refer to the Reset circuit section of FUNCTIONAL DESCRIPTION.

		R/W								
A0	RD	WR	D7	D6	D5	D4	D3	D2	D1	D0
0	1	0	1	1	1	0	0	0	1	0

The Reset command cannot initialize LCD power supply. Only the Reset signal to the RES pin can initialize the supplies.

### (15) Output Status Select Register

Applicable to the SED1530 and SED1532. When D is high or low, the scan direction of the COM output pin is selectable. Refer to Output Status Selector Circuit in Functional Description for details.

	E	R/W								
A0	RD	WR	D7	D6	D5	D4	D3	D2	D1	D0
0	1	0	1	1	0	0	D	*	*	*

D: Selects the scan direction of COM output pin

\*: Invalid bit

### (16) Set Power Control

Selects one of eight power circuit functions using 3-bit register. An external power supply and part of on-chip power circuit can be used simultaneously. Refer to Power Supply Circuit section of FUNCTIONAL DESCRIPTION for details.

A0	$\frac{E}{RD}$	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0
0	1	0	0	0	1	0	1	A2	A1	A0

When A0 goes low, voltage follower turns off. When A0 goes high, it turns on.

When A1 goes low, voltage regulator turns off. When A1 goes high, it turns on.

When A2 goes low, voltage booster turns off. When A2 goes high, it turns on.

### (17) Set Electronic Control

Adjusts the contrast of LCD panel display by changing V5 LCD drive voltage that is output by voltage regulator of on-board power supply.

This command selects one of 32 V5 LCD drive voltages by storing data in 5-bit register. The V5 voltage adjusting range should be determined depending on the external resistance. Refer to the Voltage Regulator section of FUNCTIONAL DESCRIPTION for details.

		R/W								
A0	RD	WR	D7	D6	D5	D4	D3	D2	D1	D0
0	1	0	1	0	0	A4	А3	A2	A1	A0

D4	D3	D2	D1	D0	V5
0	0	0	0	0	Low
0	0	0	0	1	
0	0	0	1	0	
		:			↓
1	1	1	0	1	
1	1	1	1	0	
1	1	1	1	1	High

Set register to (D4,D3,D2,D1,D0)=(0,0,0,0,0) to suppress electronic control function.

### (18) Static Indicator

This command turns on or off static drive indicators. The indicator display is controlled by this command only, and it is not affected by the other display control commands.

Either FR or FRS terminal is connected to either of static indicator LCD drive electrodes, and the remaining terminal is connected to another electrode. When the indicator is turned on, the static drive operates and the indicator blinks at an interval of approximately one second. The pattern separation between indicator electrodes are dynamic drive electrodes is recommended. A closer pattern may cause an LCD and electrode deterioration.

A0	E RD	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0
0	1	0	1	0	1	0	1	1	0	D

D 0: Static indicator OFF

1: Static indicator ON

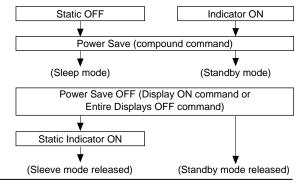
### (19) Power Save (Compound Command)

When all displays are turned on during indicator off, the Power Save command is issued to greatly reduce the current consumption.

If the static indicators are off, the Power Save command sleeps the system. If on, this command stands by the system.

Release the Sleep mode using the both Power Save OFF command (Indicator ON command or All Indicator Displays OFF command) and Static Indictor ON command.

Release the Standby mode using the Power Save OFF command (Indicator ON command or All Indicator Displays OFF command).



### Sleep mode

This mode stops every operation of the LCD display system, and can reduce current consumption nearly to a static current value if no access is made from the microprocessor. The internal status in the sleep mode is as follows:

- (1) Stops the oscillator circuit and LCD power supply circuit.
- (2) Stops the LCD drive and outputs the VDD level as the segment/common driver output.
- (3) Holds the display data and operation mode provided before the start of the sleep mode.
- (4) The MPU can access to the built-in display RAM.

### Standby mode

Stops the operation of the duty LCD display system and turns on only the static drive system to reduce current consumption to the minimum level required for static drive.

The ON operation of the static drive system indicates that the SED1530 series is in the standby mode. The internal status in the standby mode is as follows:

- (1) Stops the LCD power supply circuit.
- (2) Stops the LCD drive and outputs the VDD level as the segment/common driver output. However, the static drive system operates.
- (3) Holds the display data and operation mode provided before the start of the standby mode.
- (4) The MPU can access to the built-in display RAM. When the RESET command is issued in the standby mode, the sleep mode is set.

When the LCD drive voltage level is given by an external resistive driver, the current of this resistor must be cut so that it may be fixed to floating or VDD level, prior to or concurrently with causing the 1530 series to go to the sleep mode or standby mode

When an external power supply is used, likewise, the function of this external power supply must be stopped so that it may be fixed to floating or VDD level, prior to or concurrently with causing the SED1530 series to go to the sleep mode or standby mode

When the common driver SED1635 or SED1651 is combined with the SED1531 in the configuration, the  $\overline{DOF}$  pin of the SED1531 must be connected to the  $\overline{DOFF}$  pin of the SED1635 or SED1651.

### (20) Test Command

This is the dedicate IC chip test command. It must not be used for normal operation. If the Test command is issued erroneously, set the  $\overline{\text{RES}}$  input to low or issue the Reset command to release the test mode.

A0	E RD	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0
0	1	0	1	1	1	1	*	*	*	*

\*: Invalid bit

Cautions: The SED1530 Series holds an operation status speci-

fied by each command. However, the internal operation status may be changed by a high level of ambient noise. It must be considered to suppress the noise on the its package and system or to prevent an ambient noise insertion. To prevent a spike noise, a built-in software for periodical status refreshment is recommended to use.

The test command can be inserted in an unexpected place. Therefore, it is recommended to enter the test mode reset command F0h during the refresh sequence.

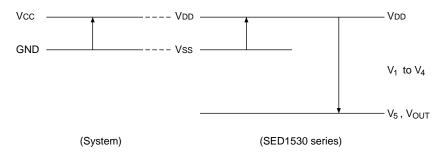
Command         Code           A0         RD         WR         D7         D6         D5         D4												
Command	A0	RD	WR	D7	D6	т —	_	D3	D2	D1	D0	Function
(1) Display ON/OFF	0	1	0	1	0	1	0	1	1	1	0	Turns on LCD panel when goes high, and turns off when goes low.
(2) Initial Display Line	0	1	0	0	1	Start	displa	ay add	dress		•	Specifies RAM display line for COM0.
(3) Set Page Address	0	1	0	1	0	1	1	Pag	je add	ress		Sets the display RAM page in Page Address register.
(4) Set Column Address 4 higher bits	0	1	0	0	0	0	1	High addr	er col ess	umn		Sets 4 higher bits of column address of display RAM in register
(4) Set Column Address 4 lower bits	0	1	0	0	0	0	0	address			Sets 4 lower bits of column address of display RAM in register	
(5) Read Status	0	0	1	Statu	IS			0	0	0	0	Reads the status information.
(6) Write Display Data	1	1	0	Write	data							Writes data in display RAM.
(7) Read Display Data	1	0	1	Read	d data						Reads data from display RAM.	
(8) ADC Select	0	1	0	1	0	1	0	0	0	0	0	Sets normal relationship between RAM column address and seg- ment driver when low, but re- verses the relationship when high.
(9) Normal/Reverse Display	0	1	0	1	0	1	0	0	1	1	0 1	Normal indication when low, but full indication when high.
(10) Entire Display ON/OFF	0	1	0	1	0	1	0	0	1	0	0 1	Selects normal display (0) or Entire Display ON (1).
(11) Set LCD Bias	0	1	0	1	0	1	0	0	0	1	0	Sets LCD drive voltage bias ratio.
(12) Read-Modify-Write	0	1	0	1	1	1	0	0	0	0	0	Increments Column Address counter during each write when high and during each read when low.
(13) End	0	1	0	1	1	1	0	1	1	1	0	Releases the Read-Modify-Write.
(14) Reset	0	1	0	1	1	1	0	0	0	1	0	Resets internal functions.
(15) Set Output Status Register	0	1	0	1	1	0	0	0	*	*	*	Selects COM output scan direction. * Invalid data
(16) Set Power Control	0	1	0	0	0	1	0	1	Oper	ration		Selects the power circuit operation mode.
(17) Set Electronic Control Register	0	1	0	1	0	0	Elec	ectronic control value		е	Sets V5 output voltage to Electronic Control register.	
(18) Set Standby	0	1	0	1	0	1	0	1 1 0 0		0	Selects standby status. 0: OFF 1: ON	
(19) Power Save	-	-	-	_	-	-	-	-	-	-	-	Compound command of display OFF and entire display ON
(20) Test Command	0	1	0	1	1	1	1	1 * * * * IC Test command. Do not		IC Test command. Do not use!		
(21) Test Mode Reset	0	1	0	1	1	1	1	0	0	0	0	Command of test mode reset

Note: Do not use any other command, or the system malfunction may result.

5–22 **EPSON** 

### **ABSOLUTE MAXIMUM RATINGS**

Parameter	r	Symbol	Rating	Unit
			-0.3 to +7.0	
Supply voltage range	Triple boosting	$V_{DD}$	-0.3 to +6.0	V
	Quadruple boosting		-0.3 to +4.5	
Supply voltage range (1) (\	/ <sub>DD</sub> Level)	V <sub>5</sub> , V <sub>OUT</sub>	-18.0 to +0.3	V
Supply voltage range (2) (\	/ <sub>DD</sub> Level)	$V_1, V_2, V_3, V_4$	V <sub>5</sub> to +0.3	V
Input voltage range		$V_{IN}$	-0.3 to V <sub>DD</sub> +0.3	V
Output voltage range		Vo	-0.3 to V <sub>DD</sub> +0.3	V
Operating temperature ran-	ge	T <sub>OPR</sub>	-40 to +85	°C
Storage temperature range	TCP	Тото	-55 to +100	- °C
Storage temperature range	Bear chip	T <sub>STR</sub>	-55 to +125	



- - 3. If an LSI exceeds its absolute maximum rating, it may be damaged permanently. It is desirable to use it under electrical characteristics conditions during general operation. Otherwise, an LSI malfunction or reduced LSI reliability may result.

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### **ELECTRICAL CHARACTERISTICS**

### **DC Characteristics**

 $V_{SS}$  = 0 V,  $V_{DD}$  = 5 V  $\pm 10\%,\, Ta$  = -40 to +85°C unless otherwise noted.

	Item		Symbol	Co	ndition	Min.	Тур.	Max.	Unit	Pin used
Р	ower voltage (1)	Recommended Operation	V <sub>DD</sub>			4.5	5.0	5.5	V	V <sub>SS</sub> *1
		Operational				2.4	_	6.0		
0	perating voltage	Operational	V <sub>5</sub>	VDD level (V	<sub>DD</sub> = 0 V)	-16.0	-	-4.5	V	V <sub>5</sub> *2
	(2)	Operational	V <sub>1</sub> , V <sub>2</sub>	VDD level (V	<sub>DD</sub> = 0 V)	0.4 × V <sub>5</sub>	_	V <sub>DD</sub>	V	V <sub>1</sub> , V <sub>2</sub>
		Operational	V <sub>3</sub> , V <sub>4</sub>	VDD level (V	<sub>DD</sub> = 0 V)	V <sub>5</sub>	_	0.6 × V <sub>5</sub>	V	V <sub>3</sub> , V <sub>4</sub>
	High-level input	voltage	V <sub>IHC</sub>			$0.7 \times V_{DD}$	_	V <sub>DD</sub>	V	*3
				V <sub>DD</sub> = 2.7 V		$0.8 \times V_{DD}$	_	V <sub>DD</sub>		*3
	Low-level input	voltage	V <sub>ILC</sub>			V <sub>SS</sub>	-	$0.3 \times V_{DD}$	V	*3
CMOS				V <sub>DD</sub> = 2.7 V		V <sub>SS</sub>	_	$0.2 \times V_{DD}$		*3
S	High-level outpu	ıt voltage	V <sub>OHC</sub>	I <sub>OH</sub> = -1 mA		$0.8 \times V_{DD}$	_	V <sub>DD</sub>	V	*5
				V <sub>DD</sub> = 2.7 V	$I_{OH} = -0.5 \text{ mA}$	$0.8 \times V_{DD}$	_	V <sub>DD</sub>		*5
	Low-level output	t voltage	Volc	I <sub>OL</sub> = 1 mA		V <sub>SS</sub>	-	$0.2 \times V_{DD}$	V	*5
				V <sub>DD</sub> = 2.7 V,	I <sub>OL</sub> = 0.5 mA	V <sub>SS</sub>	_	$0.2 \times V_{DD}$		*5
	High-level input	voltage	V <sub>IHS</sub>			$0.85 \times V_{DD}$	_	V <sub>DD</sub>		*4
Schmitt				V <sub>DD</sub> = 2.7 V		$0.8 \times V_{DD}$	_	V <sub>DD</sub>		*4
Sch	Low-level input	voltage	V <sub>ILS</sub>			V <sub>SS</sub>	_	$0.15 \times V_{DD}$		*4
				V <sub>DD</sub> = 2.7 V		V <sub>SS</sub>	-	$0.2 \times V_{DD}$		*4
In	put leakage curre	nt	ILI	VIN = V <sub>DD</sub> or	·V <sub>SS</sub>	-1.0	_	1.0	μΑ	*6
0	utput leakage curr	rent	I <sub>LO</sub>			-3.0	_	3.0	μΑ	*7
L	CD driver ON resis	stance	R <sub>ON</sub>	Ta = 25°C	V <sub>5</sub> = -14.0 V	_	2.0	3.0	ΚΩ	SEG n
				V <sub>DD</sub> level	V <sub>5</sub> = -8.0 V	_	3.0	4.5		COM n *8
St	atic current consu	ımption	I <sub>SSQ</sub>	VIN = V <sub>DD</sub> or	V <sub>SS</sub>	_	0.01	5.0	μΑ	V <sub>SS</sub>
			I <sub>5Q</sub>	V <sub>5</sub> = -18.0 \	/ (V <sub>DD</sub> level)	_	0.01	15.0	μΑ	V <sub>5</sub>
In	put pin capacity		C <sub>IN</sub>	Ta = 25°C, f	= 1 MHz	_	5.0	8.0	pF	*3 *4
0	scillation frequenc	у	fosc	Ta = 25°C	V <sub>DD</sub> = 5 V	18	22	26	kHz	*9
					V <sub>DD</sub> = 2.7 V	18	22	26		

	Item	Symbol	Condition	Min.	Тур.	Max.	Unit	Pin used
	Input voltage	V <sub>DD</sub>	Triple boosting	2.4	-	6.0	V	*10
Ļ			Quadruple boosting	2.4	_	4.5		
circuit	Booster output voltage	V <sub>OUT</sub>	Triple voltage conversion (VDD level)	-18.0	_	_	V	V <sub>OUT</sub>
power	Voltage regulator operation	V <sub>OUT</sub>	(VDD level)	-18.0	_	-6.0	V	V <sub>OUT</sub>
	voltage							
Built-in	Voltage follower operation	V5	(VDD level)	-18.0	_	-6.0	V	*11
В	voltage			-16.0	_	-4.5	V	
	Reference voltage	V <sub>REG</sub>	Ta = 25°C (VDD level)	-2.75	-2.55	-2.35	V	

For the mark \*, refer to P. 1-25

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### Dynamic current consumption (1) when the built-in power supply is OFF

Ta = 25°C

Item	Symbol	Condition	Min.	Тур.	Max.	Unit	Note
SED1530/		$V_{DD} = 5.0V, V_5 - V_{DD} = -8.0 V$	_	24	40		
SED1535		$V_{DD} = 3.0V, V_5 - V_{DD} = -8.0 V$	_	22	35		
SED1531		$V_{DD} = 5.0V, V_5 - V_{DD} = -11.0 V$	_	40	65		
	I <sub>DD</sub>	$V_{DD} = 3.0V, V_5 - V_{DD} = -11.0 V$	_	36	60		*12
SED1532	(1)	$V_{DD} = 5.0V, V_5 - V_{DD} = -11.0 V$	_	39	65	μΑ	12
		$V_{DD} = 3.0V, V_5 - V_{DD} = -11.0 V$	_	32	55		
SED1533		$V_{DD} = 3.0V, V_5 - V_{DD} = -5.0 V$	_	20	35		
SED1534		$V_{DD} = 3.0V, V_5 - V_{DD} = -5.0 V$	_	20	35		

### Dynamic current consumption (2) when the built-in power supply is ON

Ta = 25°C

Item	Symbol	Condition	Min.	Тур.	Max.	Unit	Note
SED1530/		$V_{DD} = 5.0V$ , $V_5 - V_{DD} = -8.0$ V, dual boosting	_	41	70		
SED1535		$V_{DD} = 3.0V$ , $V_5 - V_{DD} = -8.0 V$ , triple boosting	_	48	80		
SED1531		$V_{DD} = 5.0V$ , $V_5 - V_{DD} = -11.0$ V, triple boosting	_	96	160		
	I <sub>DD</sub>	$V_{DD} = 3.0V$ , $V_5 - V_{DD} = -11.0$ V, quadruple boosting	_	118	190	^	*13
SED1532	(1)	$V_{DD} = 5.0V$ , $V_5 - V_{DD} = -11.0$ V, triple boosting	_	95	160	μΑ	13
		$V_{DD} = 3.0V$ , $V_5 - V_{DD} = -11.0$ V, quadruple boosting	_	114	190		
SED1533		$V_{DD} = 3.0V$ , $V_5 - V_{DD} = -5.0$ V, dual boosting	_	30	50		
SED1534		$V_{DD} = 3.0V$ , $V_5 - V_{DD} = -5.0$ V, dual boosting	_	32	55		

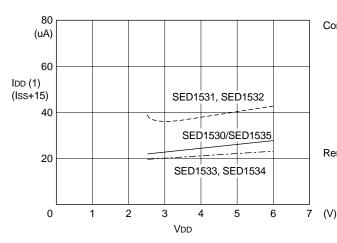
### **Current consumption during Power Save mode**

 $V_{SS} = 0 \text{ V}, V_{DD} = 2.7 \text{ to } 5.5 \text{ V} \text{ Ta}=25^{\circ}\text{C}$ 

				- 55	-, - 00 -		
Item	Symbol	Condition	Min.	Тур.	Max.	Unit	Note
During sleep	I <sub>DDS1</sub>	SED1530, SED1531, SED1532	_	0.01	1	uΑ	
During standby	I <sub>DDS2</sub>	SED1530, SED1531, SED1532	_	10	20	μπ	

### Typical current consumption characteristics (reference data)

 Dynamic current consumption (1) when LCD external power mode lamp is ON



Condition: The built-in power supply is OFF and an external power

supply is used.

SED1530/SED1535 V5-VDD=-8.0V

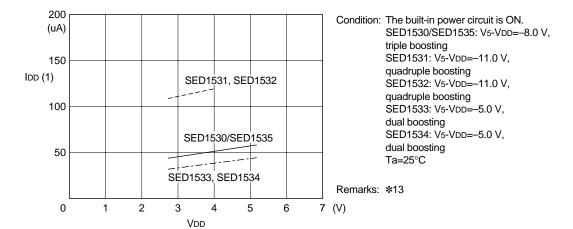
SED1531 V5-VDD=-11.0V SED1532 V5-VDD=-11.0V SED1533 V5-VDD=-6.0V SED1534 V5-VDD=-6.0V

Ta=25°C

Remarks: \*12

### SED1530 Series

 Dynamic current consumption (2) when the LCD built-in power circuit lamp is ON



- \*1 Though the wide range of operating voltages is guaranteed, a spike voltage change may affect the voltage assurance during access from the microprocessor.
- \*2 V<sub>DD</sub> and V<sub>5</sub> operating voltage range. (Refer to Fig. 10.) The operating voltage range applies if an external power supply is used.
- \*3 A0, D0 D5, D6, D7 (SI), RD (E), WR (R/W), CS1, CS2, FR, M/S, C86, P/S and DOF pins
- \*4 CL, SCL (D6) and RES pins
- \*5 D0 D5, D6, D7 (SI), FR, FRS, DYO, DOF and CL pins
- \*6 A0, RD (E), WR (R/W), CS1, CS2, M/S, RES, C86 and P/S pins
- \*7 Applies when the D0 D7, FR, CL, DYO and  $\overline{\text{DOF}}$  pins are in high impedance,
- \*8 Resistance value when 0.1 V is applied between the output pin SEGn or COMn and each power supply pin (V1, V2, V3, V4). This is specified in the operating voltage (2) range.
  R ON = 0.1 V/ΔI (ΔI: Current flowing when 0.1 V is applied in the ON status.)
- \*9 For the relationship between oscillation frequency and frame frequency, refer to Fig. 9.
- \*10 For triple or quadruple boosting using the on-chip power useing the primary-side power supply V<sub>DD</sub> must be used within the input voltage range.
- \*11 The voltage regulator adjusts V<sub>5</sub> within the voltage follower operating voltage range.
- \*12, \*13 Current that each IC unit consumes. It does not include the current of the LCD panel capacity, wiring capacity, etc.

  This is current consumption under the conditions of display data = checker, display ON, SED1530 = 1/33 duty (1/6 Bias), and SED1531 and SED1532 = 1/65 duty. (1/8 Bias)
- \*12 Applies to the case where the on-chip oscillator circuit is used and no access is made from the microprocessor.
- \*13 Applies to the case where the on-chip oscillator circuit and the on-chip power circuit are used and no access is made from the microprocessor.

The current flowing through voltage regulation resistors (R1, R2 and R3) is not included.

The current consumption, when the on-chip voltage booster is used, is for the power supply  $V_{DD}$ .

· Relationship between oscillation frequency and frame frequency

The relationship between oscillation frequency f<sub>OSC</sub> and LCD frame frequency, f<sub>F</sub> can be obtained by the following expression.

	Duty	f CL	f F
SED1530	1/33	f osc/8	f osc/(8*33)
SED1531	1/65	f osc/4	f osc/(4*65)
SED1532	1/00	1 050/4	1 080/(4*03)
SED1533	1/17	f osc/8	f osc/(8*17)
SED1534	1/9	f osc/8	f osc/(8*9)
SED1535	1/35	f osc/8	f osc/(8*35)

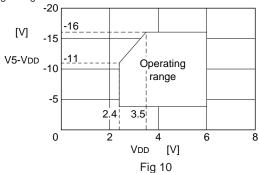
(f<sub>F</sub> does not indicate the FR signal cycle but the AC cycle.)

Fig. 9

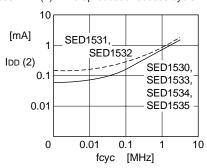
Relationship between clock (f<sub>CL</sub>) and frame frequency f<sub>F</sub>

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V<sub>SS</sub> and V<sub>5</sub> operating voltage range



• Current consumption at access IDD (2) - Microprocessor access cycle



This indicates current consumption when data is always written on the checker pattern at fcyc. When no access is made, only IDD (1) occurs.

Condition: SED1530/SED1535 V5-VDD=-8.0V, triple boosting SED1531 V5-VDD=-11.0V, quadruple boosting SED1532 V5-VDD=-11.0V, quadruple boosting SED1533 V5-VDD=-6.0V, dual boosting SED1534 V5-VDD=-6.0V, dual boosting SED1534 V5-VDD=-6.0V, dual boosting

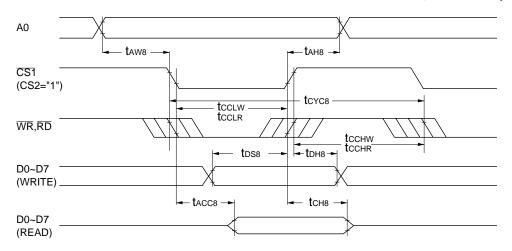
Ta = 25°C

Fig. 11

### **AC Characteristics**

(1) System buses

Read/write characteristics I (8080-series microprocessor)



 $V_{DD} = 5.0 \text{ V} \pm 10\%$ , Ta = -40 to +85°C

Parameter	Signal	Symbol	Condition	Min.	Max.	Unit
Address hold time Address setup time	A0	t <sub>AH8</sub>		10 10		ns ns
System cycle time		t <sub>CYC8</sub>		166	_	ns
Control L pulse width (WR) Control L pulse width (RD) Control H pulse width (WR) Control H pulse width (RD)	WR RD WR RD	t <sub>CCLW</sub> t <sub>CCLR</sub> t <sub>CCHW</sub> t <sub>CCHR</sub>		30 70 100 70	- - - -	ns ns ns ns
Data setup time Data hold time		t <sub>DS8</sub>		20 10		ns ns
RD access time Output disable time	D0 to D7	t <sub>ACC8</sub>	C <sub>L</sub> =100pF	_ 10	70 50	ns ns

 $V_{DD}$  = 2.7 V to 4.5 V, Ta = -40 to +85°C

Parameter	Signal	Symbol	Condition	Min.	Max.	Unit
Address hold time Address setup time	A0	t <sub>AH8</sub>		19 15	_ _	ns ns
System cycle time		t <sub>CYC8</sub>		450	_	ns
Control L pulse width (WR) Control L pulse width (RD) Control H pulse width (WR) Control H pulse width (RD)	WR RD WR RD	t <sub>CCLW</sub> t <sub>CCLR</sub> t <sub>CCHW</sub> t <sub>CCHR</sub>		60 140 200 140	- - -	ns ns ns ns
Data setup time Data hold time		t <sub>DS8</sub>		40 15	_ _	ns ns
RD access time Output disable time	D0 to D7	t <sub>ACC8</sub> t <sub>CH8</sub>	C <sub>L</sub> =100pF	_ 10	140 100	ns ns

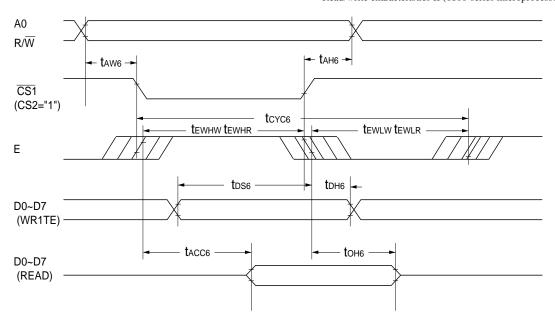
Notes: 1. The input signal rise/fall time  $(t_r, t_f)$  is specified at 15 ns or less. When system cycle time is used at a high speed, it is specified by  $t_r + t_f \le (t_{CYC8} - t_{CCLW})$  or  $t_r + t_f \le (t_{CYC8} - t_{CCLR} - t_{CCHR}).$ 

- Every timing is specified on the basis of 20% and 80% of V<sub>DD</sub>.
   t<sub>EWHR</sub> and t<sub>EWHW</sub> are specified by the overlap period in which CS1 is "0" (CS2 = "1") and WR and RD are "0".

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### (2) System buses

Read/write characteristics II (6800-series microprocessor)



 $V_{DD} = 5.0 \text{ V} \pm 10\%$ ,  $Ta = -40 \text{ to } +85^{\circ}\text{C}$ 

					00	,	
Paramete	er	Signal	Symbol	Condition	Min.	Max.	Unit
System cycle time	)		t <sub>CYC6</sub>		166	_	ns
Address setup time		A0 W/R	t <sub>AW6</sub>		10 10	_ _	ns ns
Data setup time Data hold time			t <sub>DS6</sub> t <sub>DH6</sub>		20 10	_ _	ns ns
Output disable time Access time		001007	t <sub>OH6</sub>	C <sub>L</sub> =100pF	10 _	50 70	ns ns
Enable	READ	Е	t <sub>EWHR</sub>		70	_	ns
low pulse width	WRITE		t <sub>EWHW</sub>		30	_	ns
Enable	READ	Е	t <sub>EWLR</sub>		70	_	ns
high pulse width	WRITE		t <sub>EWLW</sub>		100	_	ns

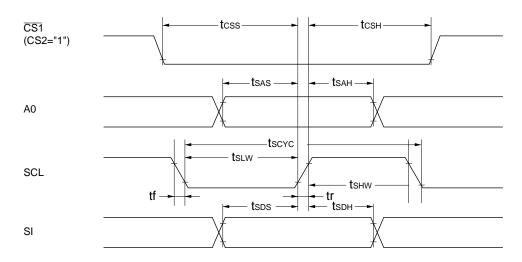
 $V_{DD}$  = 2.7 V to 4.5 V, Ta = -40 to +85°C

			1				
Paramete	er	Signal	Symbol	Condition	Min.	Max.	Unit
System cycle time	)		t <sub>CYC6</sub>		450	_	ns
Address setup time		A0 R/W	t <sub>AW6</sub>		15 19	_ _	ns ns
Data setup time Data hold time		D0 to D7	t <sub>DS6</sub> t <sub>DH6</sub>		40 15	_ _	ns ns
Output disable tim Access time	ne	50 10 57	t <sub>OH6</sub>	C <sub>L</sub> =100pF	10 _	100 140	ns ns
Enable	READ	Е	t <sub>EWHR</sub>		140	_	ns
low pulse width	WRITE	_	t <sub>EWHW</sub>		60	_	ns
Enable	READ	E	t <sub>EWLR</sub>		140	-	ns
high pulse width	WRITE	<u> </u>	t <sub>EWLW</sub>		200	-	ns

Notes: 1. The input rise/fall time  $(t_r, t_f)$  is specified at 15 ns or less. When the system cycle time is used at a high speed, it is specified by  $t_r + t_f \le (t_{CYC6} - t_{EWLW} - t_{EWHW})$  or  $t_r + t_f \le (t_{CYC6} - t_{EWLR} - t_{EWHR})$ .

- 2. Every timing is specified on the basis of 20% and 80% of  $V_{DD}$ .
- 3. t<sub>EWHR</sub> and t<sub>EWHW</sub> are specified by the overlap period in which CS1 is "0" (CS2 = "1") and E is "1".

### (3) Serial interface



 $V_{DD}$  = 5.0 V ±10%, Ta = -40 to +85°C

Parameter	Signal	Symbol	Condition	Min.	Max.	Unit
Serial clock cycle Serial clock H pulse width Serial clock L pulse width	SCL	t <sub>SCYC</sub> t <sub>SHW</sub> t <sub>SLW</sub>		250 100 75	_ _ _	ns ns ns
Address setup time Address hold time	A0	t <sub>SAS</sub> t <sub>SAH</sub>		50 200	_ _	ns ns
Data setup time Data hold time	SI	t <sub>SDS</sub>		50 50		ns ns
CS serial clock time	CS	t <sub>CSS</sub> t <sub>CSH</sub>		30 100		ns

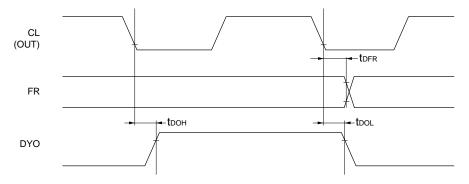
 $V_{DD}$  = 2.7 to 4.5V, Ta = -40 to +85°C

Parameter	Signal	Symbol	Condition	Min.	Max.	Unit
Serial clock cycle Serial clock H pulse width Serial clock L pulse width	SCL	t <sub>SCYC</sub> t <sub>SHW</sub> t <sub>SLW</sub>		500 200 150	- - -	ns ns ns
Address setup time Address hold time	A0	t <sub>SAS</sub> t <sub>SAH</sub>		100 400	_ _	ns ns
Data setup time Data hold time	SI	t <sub>SDS</sub>		100 100	_ _	ns ns
CS serial clock time	CS	t <sub>CSS</sub>		60 200	_ _	ns

Notes: 1. The input signal rise and fall times must be within 15 nanoseconds. 
2. All signal timings are limited based on 20% and 80% of  $V_{\rm DD}$  voltage.

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### (4) Display control timing



### **Output timing**

$$V_{DD} = 5.0 \text{ V} \pm 10\%$$
,  $Ta = -40 \text{ to } +85^{\circ}\text{C}$ 

Parameter	Signal	Symbol	Condition	Min.	Тур.	Max.	Unit
FR delay time	FR	t <sub>DFR</sub>	C <sub>L</sub> = 50 pF	_	10	40	ns
DYO "H" delay time	DYO	t <sub>DOH</sub>		_	40	100	ns
DYO "L" delay time		t <sub>DOL</sub>		-	40	100	ns

### **Output timing**

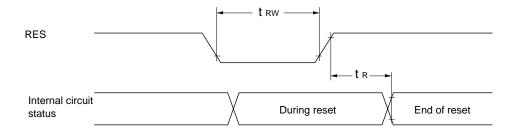
$$V_{SS} = 0 \text{ V}, V_{DD} = 2.7 \text{ V} \text{ to } 4.5 \text{ V}, Ta = -40 \text{ to } +85^{\circ}\text{C}$$

Parameter	Signal	Symbol	Condition	Min.	Тур.	Max.	Unit
FR delay time	FR	t <sub>DFR</sub>	C <sub>L</sub> = 50 pF	_	15	80	ns
DYO "H" delay time	DYO	t <sub>DOH</sub>		_	70	200	ns
DYO "L" delay time		t <sub>DOL</sub>		_	70	200	ns

Notes: 1. The otput timing is valid in master mode.

2. Every timing is specified on the basis of 20% and 80% of V<sub>DD</sub>.

### (5) Reset timing



$$V_{DD} = 5.0 \text{ V} \pm 10\%$$
,  $Ta = -40 \text{ to } +85^{\circ}\text{C}$ 

Parameter	Signal	Symbol	Condition	Min.	Тур.	Max.	Unit
Reset time		t <sub>R</sub>		0.5	_	-	μs
Reset low pulse width	RES	t <sub>RW</sub>		0.5	-	-	μs

 $V_{DD} = 2.7 \text{ V to } 4.5 \text{ V}, \text{ Ta} = -40 \text{ to } +85^{\circ}\text{C}$ 

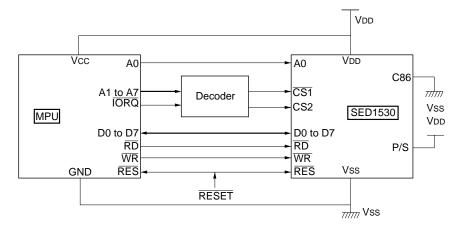
Parameter	Signal	Symbol	Condition	Min.	Тур.	Max.	Unit
Reset time		t <sub>R</sub>		1.0	_	_	μs
Reset low pulse width	RES	t <sub>RW</sub>		1.0	_	-	μs

Note: The reset timing is specified on the basis of 20% and 80% of  $V_{\rm DD}$ .

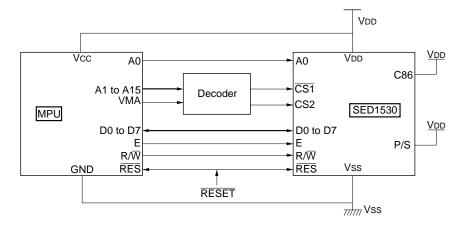
### **MICROPROCESSOR INTERFACE (Reference example)**

The SED1530 series chips can directly connect to 8080 and 6800-series microprocessors. Also, serial interfacing requires less signal lines between them. When multiple chips are used in the SED1530 series they can be connected to the microprocessor and one of them can be selected by Chip Select.

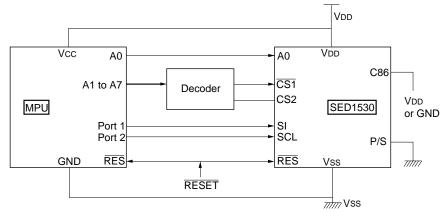
### 8080-series microprocessors



### 6800-series microprocessors



### Serial interface

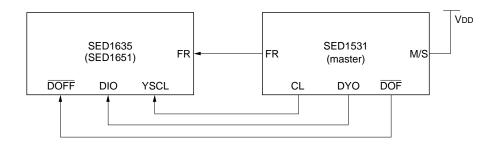


5–32 **EPSON** 

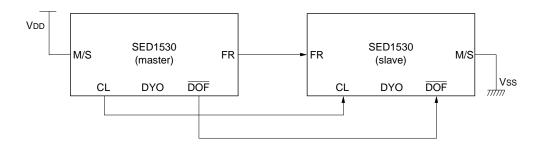
### **CONNECTION BETWEEN LCD Drivers**

The LCD panel display area can easily be expanded by use of multiple SED1530 series chips. The SED1530 series can also be connected to the common driver (SED1635).

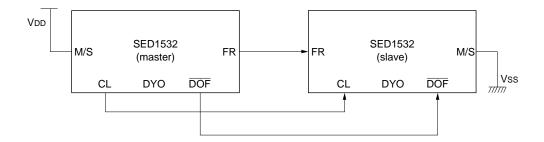
### SED1531 to SED1635 (SED1651)

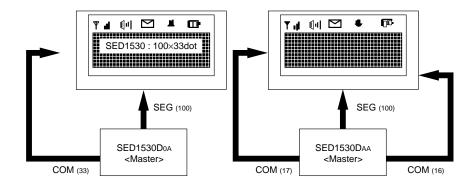


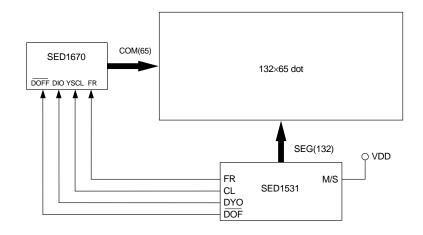
### SED1530 to SED1531

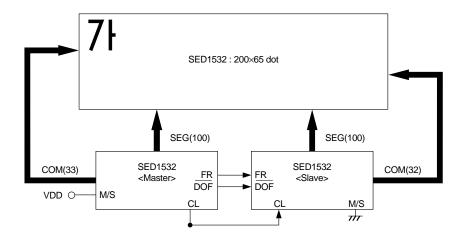


### SED1532 to SED1532









5–34 **EPSON** 

### Dimensional outline drawing of the flexible substrate

(an example) The dimensions are subject to change without prior notice.

